NSN 5961-01-033-9378

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-033-9378 **Inclosure Material:** Metal **Overall Length:** 0.380 inches **Overall Diameter:** 0.505 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 20.00 amperes drain current horsepower metric **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector outside diameter **Maximum Operating Tempurature Per Measurement Point:** 105.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0